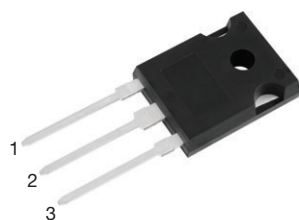
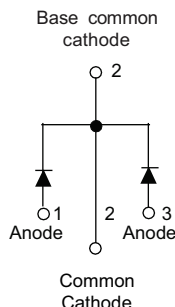


650 V Power SiC Gen 3 Merged PIN Schottky Diode, 2 x 8 A


TO-247AD 3L


FEATURES

- Majority carrier diode using Schottky technology on SiC wide band gap material
- Improved V_F and efficiency by thin wafer technology
- Positive V_F temperature coefficient, for easy paralleling
- Virtually no recovery tail and no switching losses
- Temperature invariant switching behavior
- 175 °C maximum operating junction temperature
- MPS structure for high ruggedness to forward current surge events
- Meets JESD 201 class 1A whisker test
- Solder Bath temperature 275 °C maximum, 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

LINKS TO ADDITIONAL RESOURCES


[3D Models](#)

[Application Notes](#)

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 8 A
V_R	650 V
V_F at I_F at 150 °C	1.5 V
T_J max.	175 °C
I_R at V_R at 175 °C	1.9 μ A
Q_C ($V_R = 400$ V)	22 nC
Package	TO-247AD 3L
Circuit configuration	Common cathode

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters.

MECHANICAL DATA

Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

Mounting torque: 10 in-lbs maximum

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		650	V
Average rectified forward current, per leg	$I_{F(AV)}$	$T_C = 135$ °C (DC)	8	A
DC blocking voltage	V_{DC}		650	V
Repetitive peak forward current	I_{FRM}	$T_C = 25$ °C, $f = 50$ Hz, square wave, DC = 25 %	35	A
Non-repetitive peak forward surge current, per leg	I_{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, half sine wave	54	
		$T_C = 110$ °C, $t_p = 10$ ms, half sine wave	52	
Power dissipation, per leg	$P_{tot}^{(1)}$	$T_C = 25$ °C	58	W
		$T_C = 110$ °C	25	
I^2t value, per leg	$\int i^2 dt$	$T_C = 25$ °C	13.5	A ² s
		$T_C = 110$ °C	12.5	
Operating junction and storage temperatures	$T_J^{(2)}, T_{Stg}$		-55 to +175	°C

Notes

(1) Based on maximum R_{th}

(2) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{thJA}$

**ELECTRICAL SPECIFICATIONS** ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Forward voltage, per leg	V_F	$I_F = 8\text{ A}$	-	1.3	1.5	V
		$I_F = 8\text{ A}, T_J = 150\text{ }^{\circ}\text{C}$	-	1.5	1.8	
		$I_F = 8\text{ A}, T_J = 175\text{ }^{\circ}\text{C}$	-	1.58	-	
Reverse leakage current, per leg	I_R	$V_R = V_R\text{ rated}$	-	0.25	45	μA
		$V_R = V_R\text{ rated}, T_J = 150\text{ }^{\circ}\text{C}$	-	1.1	100	
		$V_R = V_R\text{ rated}, T_J = 175\text{ }^{\circ}\text{C}$	-	1.9	-	
Total capacitance, per leg	C	$V_R = 1\text{ V}, f = 1\text{ MHz}$	-	340	-	pF
		$V_R = 400\text{ V}, f = 1\text{ MHz}$	-	34	-	
Total capacitive charge, per leg	Q_C	$V_R = 400\text{ V}, f = 1\text{ MHz}$	-	22	-	nC

THERMAL - MECHANICAL SPECIFICATIONS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	per leg	R_{thJC}		-	2.0	2.6	$^{\circ}\text{C/W}$
	per device			-	1.0	1.3	$^{\circ}\text{C/W}$
Marking device				3C16CP07L			

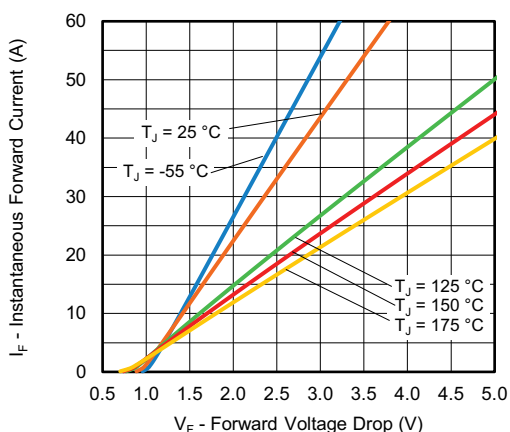


Fig. 1 - Typical Forward Voltage Drop Characteristics, Per Leg

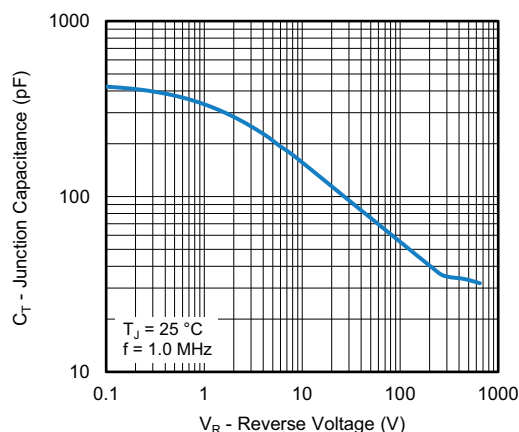


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

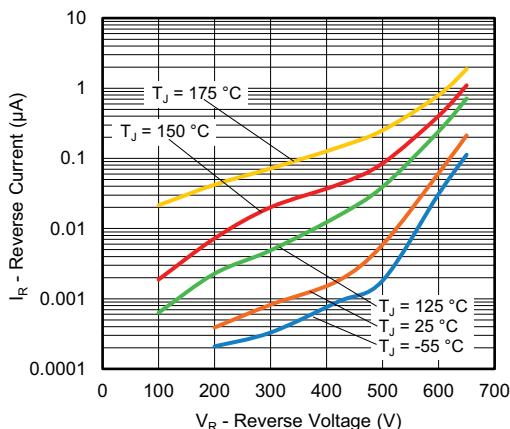


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg

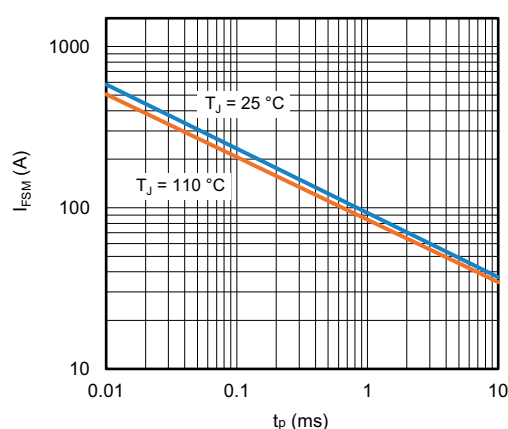


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration, Per Leg (Square Wave)

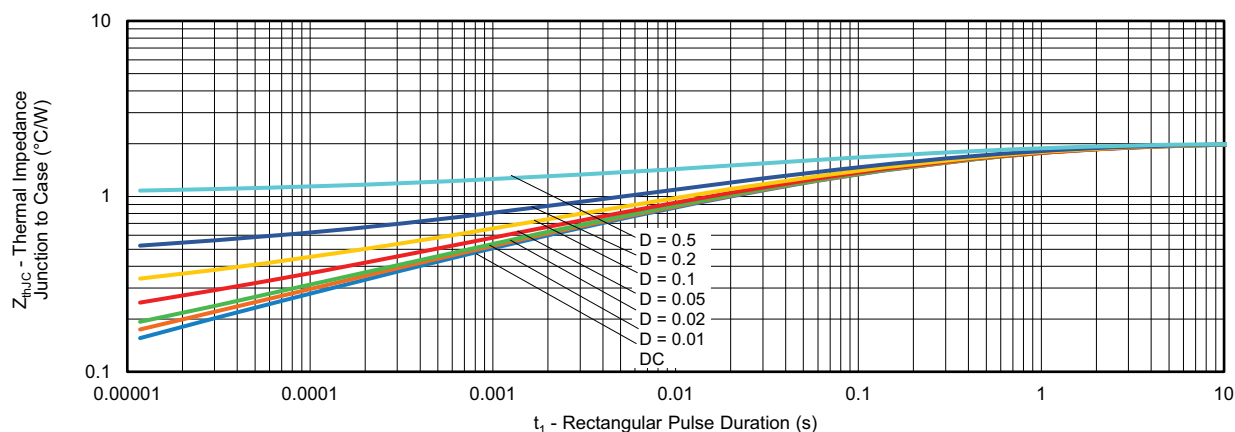
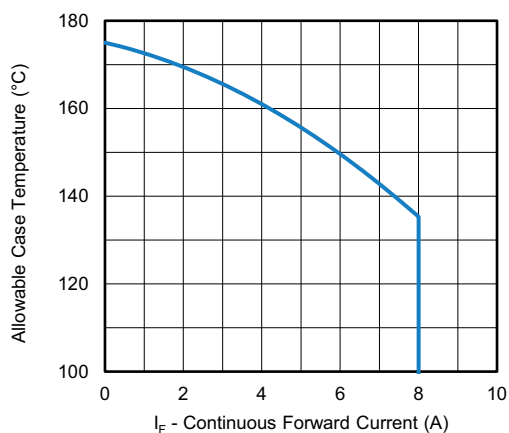

Fig. 5 - Typical Thermal Impedance Z_{thJC} Characteristics, Per Leg


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Leg

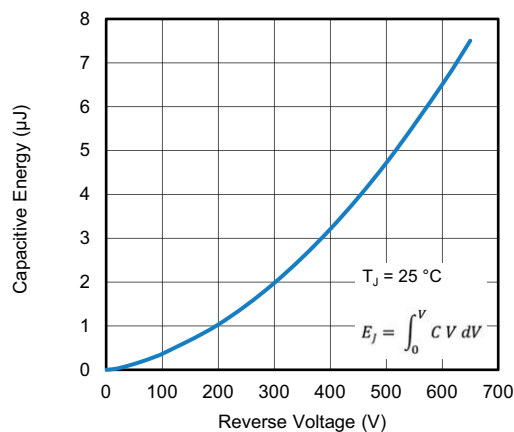


Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage, Per Leg

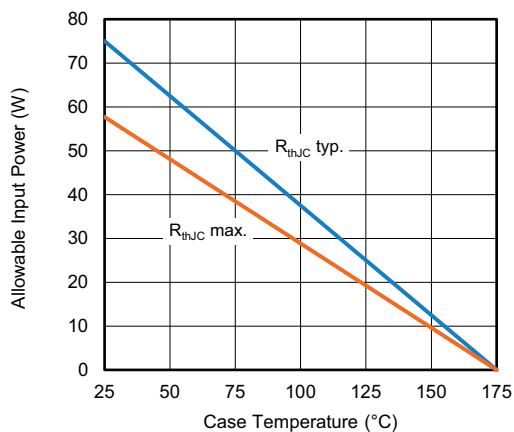


Fig. 7 - Forward Power Loss Characteristics, Per Leg

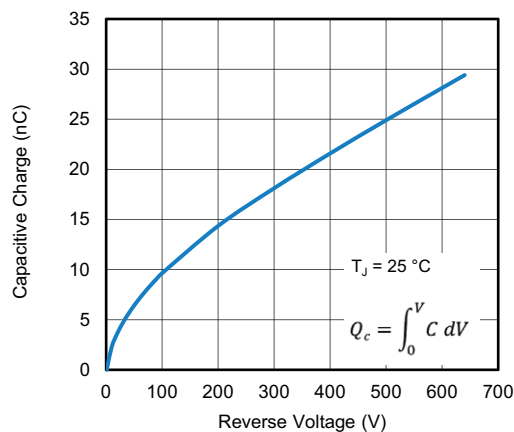


Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage, Per Leg



ORDERING INFORMATION TABLE

Device code	VS-	3C	16	C	P	07	L	-M3
	1	2	3	4	5	6	7	8

- | | | |
|---|---|--|
| 1 | - | Vishay Semiconductors product |
| 2 | - | 3C = SiC diode, Generation 3 |
| 3 | - | Current rating (16 = 16 A) |
| 4 | - | C = common cathode |
| 5 | - | P = package TO-247 |
| 6 | - | Voltage rating: (07 = 650 V) |
| 7 | - | L = long lead |
| 8 | - | Environmental digit:
-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free |

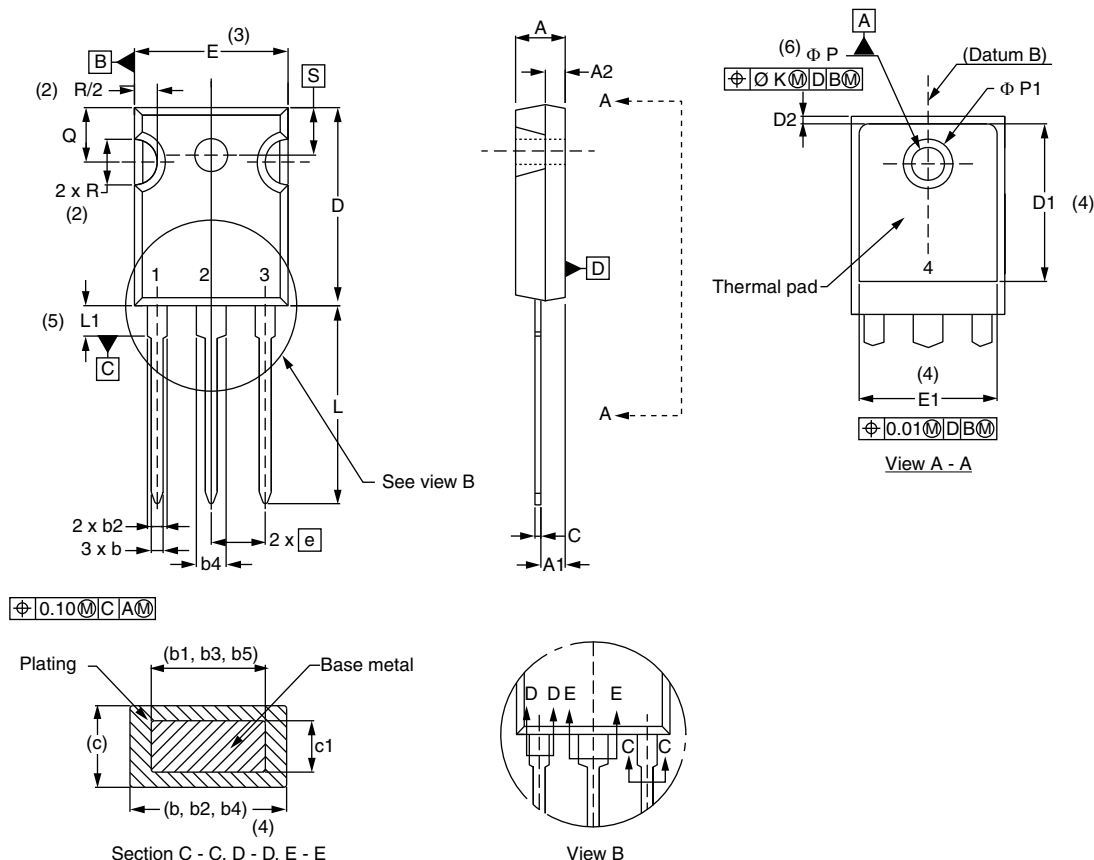
ORDERING INFORMATION		
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-3C16CP07L-M3	25/tube	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95626
Part marking information	www.vishay.com/doc?95007



TO-247AD 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
c	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
e	5.46 BSC		0.215 BSC		
ΦK	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ΦP	3.56	3.66	0.14	0.144	
$\Phi P1$	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

Notes

- Dimensioning and tolerancing per ASME Y14.5M-1994
- Contour of slot optional
- Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- Thermal pad contour optional with dimensions D1 and E1
- Lead finish uncontrolled in L1
- ΦP to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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